

产品概览

NSR20F20NX: Schottky Barrier Diode, 2.0 A, 20 V

欲看完整文档，请参阅数据表。

The Schottky diode is optimized for low forward voltage drop and low leakage current and are offered in a Chip Scale Package (CSP) to reduce board space. The low thermal resistance enables designers to meet the challenging task of achieving higher efficiency and meeting reduced space requirements.

特性

- Low Forward Voltage Drop (VF)

应用

- Reverse Voltage & Current Protection

优势

- Better efficiency

终端产品

- Portable/Consumer Products

器件电气规格

产品	Pricing (\$/Unit)	Compliance	Status	Configuration	V_{RRM} Min (V)	V_f Max (V)	I_{RM} Max (μ A)	$I_{O(lec)}$ Max (A)	I_{FSM} Max (A)	t_{rr} Max (ns)	C_j Max (pF)	Package Type
NSR20F20NXT5G	0.1261	Pb-free Halide free non AEC-Q and PPAP	Active	Single	20	0.47	30	2	28	-	-	DSN-2

欲了解更多信息，请联系您当地的销售支援 www.onsemi.cn。

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